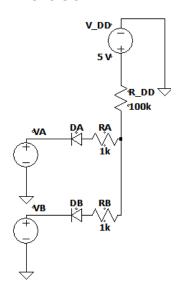
## **Basic Operation**

#### **Exercise 1**



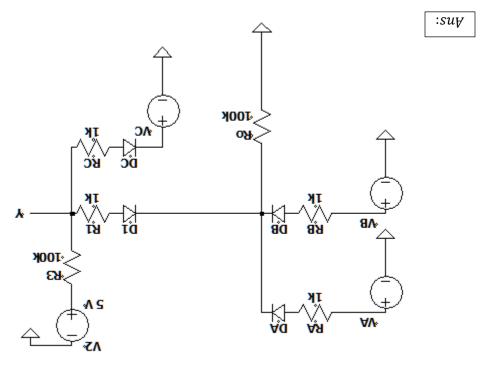
For the AND gate-

- a) For logic case (1,0), find the output voltage & verify your assumption of the diode model used.
- b) Find the current through  $R_{DD}$  for logic case (0,1).
- c) If  $R_B$  is doubled, find the currents through the diodes for logic case (O,O).
- d) Find the voltage of the node between  $D_B \& R_B$  for the case in (c)

V E47.0 (b : snh Am E40.0 (d Am 410.0, Am 820.0 (2 V 7.0 (b

## **Practice Problem 1:**

Implement the Boolean function, Y = (A+B)C using diode logic.



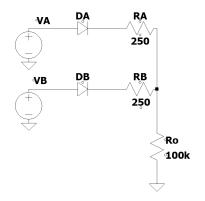
#### Exercise 2

Find the lower threshold voltage for the AND gate in **Exercise 1**, so that the output logic state can be determined correctly.

V E47.0 :2nA

# **Power Dissipation**

### **Exercise 3**



Find the power dissipation for all input logic cases.

[High input = 5 V, Low input = 0.2 V]

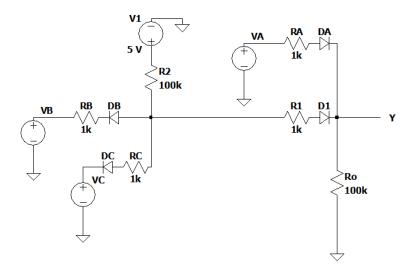
Ny 2.412, Wy 2.412, Wy 241.2, Wm 0:2nA

### **Practice Problem 2:**

Find the maximum & average power dissipation for the OR gate in Exercise 3.

Wy 2780.21, Wy 24.12:2nA

### **Exercise 4**



For the diode logic circuit given-

- a) Find the Boolean expression of Y.
- b) Determine the higher & lower threshold of output voltage.
- c) Find the maximum & average power dissipation of the full circuit.

SnA: SnA + BC D = A + BC